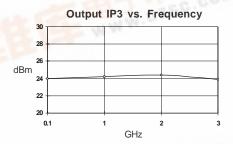


## **Product Description**

Stanford Microdevices' SCA-7 is a high performance Gallium Arsenide Hetrojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration is utilized for broadband performance up to 3 GHz. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Typical IP3 at 40mA is +24dBm.

These unconditionally stable amplifiers provides 21dB of gain and +12dBm of 1dB compressed power and requires only a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional inductor are needed for operation.

This MMIC is an ideal choice for wireless applications such as cellular, PCS, CDPD, wireless data and SONET.



### Electrical Specifications at Ta = 25C

## SCA-7

# DC-3 GHz, Cascadable GaAs HBT MMIC Amplifier



#### **Product Features**

• High Output IP3 : +24dBm

• High Gain : Up to 21dB

Cascadable 50 Ohm : 1.5:1 VSWR

• Patented GaAs HBT Technology

Operates From Single Supply

• Low Thermal Resistance Package

## **Applications**

Cellular, PCS, CDPD

Wireless Data, SONET

Symbol	Parameters: Test Conditions: Id = 40mA, Z <sub>0</sub> = 50 Ohms		Units	Min.	Тур.	Max.
G <sub>P</sub>	Power Gain	f = 0.1-2.0 GHz f = 2.0-3.0 GHz	dB dB	18	20 18	
G <sub>F</sub>	Gain Flatness Gain Flatness over any 100 MHz band	f = 0.1-2.0 GHz	dB dB		+/- 1.2 +/- 0.1	420
P <sub>1dB</sub>	Output Power at 1dB Compression:	f = 0.1-2.0 GHz	d B m	每-	12.0	SC-CC
NF	Noise Figure	f = 0.1-3.0 GHz	dB	WW.	3.8	
IP <sub>3</sub>	Third Order Intercept Point Output Tone @ 0dBm 10 MHz Apart	f = 0.1-2.0 GHz	d B m	23.0	24.0	
T <sub>D</sub>	Group Delay	f = 1.9 GHz	psec		100	
ISOL	Reverse Isolation	f = 0.1-3.0 GHz	dB		22	
V D	Device Voltage		V	3.5	4.0	4.5
dG/dT	Device Gain Temperature Coefficient		dB/degC		-0.003	
dV/dT	Device Voltage Temperature Coefficient		m V/degC		-4.0	·

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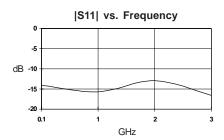
22 Almanor Ave., Sunnyvale, CA 94086

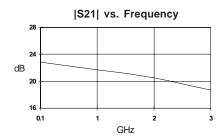
Phone: (800) SMI-MMIC

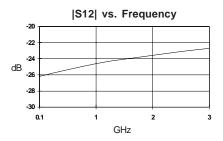


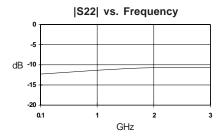
## SCA-7 DC-3 GHz Cascadable MMIC Amplifier

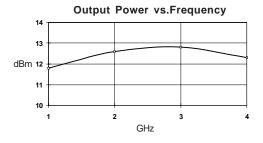
## Typical Performance at 25° C (Vds = 4.0V, Ids = 40mA)











Typical S-Parameters Vds = 4.0V, Id = 40mA

Freq GHz	S11	S11 Ang	S21	S21 Ang	S12	S12 Ang	S22	S22 Ang
.100	0.338	117	13.126	139	0.064	-19	0.326	118
.500	0.322	112	13.096	130	0.056	-25	0.317	113
.900	0.310	61	12.333	93	0.057	-46	0.320	64
1.00	0.305	47	12.165	83	0.059	-50	0.320	51
1.50	0.271	-13	11.356	38	0.062	-79	0.316	-9
2.00	0.225	-71	10.626	-7	0.066	-107	0.307	-67
2.50	0.179	-129	9.175	-52	0.070	-138	0.298	-126
3.00	0.148	172	8.363	-90	0.073	-173	0.291	177

(S-Parameters include the effects of two 1.0 mil diameter bond wires, each 20 mils long, connected to the gate and drain pads on the die)

522 Almanor Ave., Sunnyvale, CA 94086

Phone: (800) SMI-MMIC



#### **Absolute Maximum Ratings**

Parameter	A b s o lute M a x im u m
Device Current	75 m A
Power Dissipation	350 m W
RF Input Power	100 m W
Junction Temperature	+200C
Operating Temperature	-45C to +85C
Storage Temperature	-65C to +150C

#### Notes:

1. Operation of this device above any one of these parameters may cause permanent damage.

Recommended Bias Resistor Values						
Supply Voltage (Vs)	5V	7.5V	9V	12V	15V	20V
Rbias (Ohms)	25	88	125	200	275	400

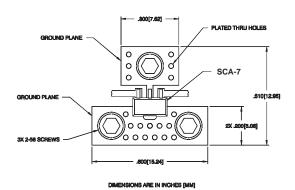
#### **Mounting Instructions**

The data shown was taken on a 31mil thick FR-4 board with

1 ounce of copper on both sides.

The board was mounted to a baseplate with 3 screws as shown. The screws bring the top side copper temperature to the same value as the baseplate.

- 1. Use 1 or 2 ounce copper, if possible.
- 2. Solder the copper pad on the backside of the device package to the ground plane.
- 3. Use a large ground pad area with many plated through-holes as shown
- 4. If possible, use at least one screw no more than 0.2 inch from the device package to provide a low thermal resistance path to the baseplate of the package.
- 5. Thermal resistance from ground lead to screws is 2 deg.  $\mbox{C/W}.$

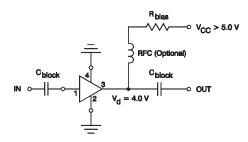


## SCA-7 DC-3 GHz Cascadable MMIC Amplifier

#### MTTF vs. Temperature @ Id = 40mA

Lead Temperature	MTTF (hrs)
+85C	1,000,000
+120C	100,000
+150C	10,000

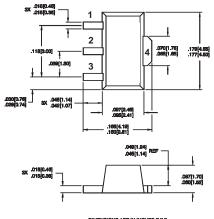
Thermal Resistance (Lead-Junction): 412 C/W



Typical Biasing Configuration

Pin Designation			
1	RF in		
2	GND		
3	RF out and Bias		
4	GND		

#### **Outline Drawing**



DIMENSIONS AFE IN INCHES [MM]

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